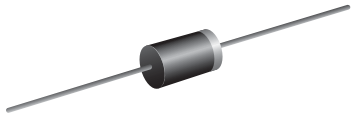
10JDA20

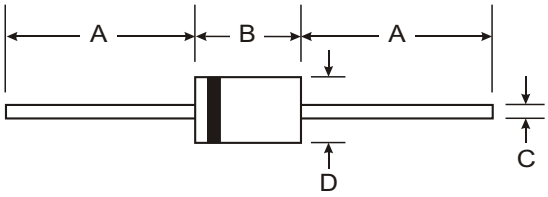
AXIAL LEADED SILICON RECTIFIER DIODES

VOLTAGE RANGE: 200V
CURRENT: 1.0 A



Features

- Miniature Size
- Low Forward Voltage drop
- Low Reverse Leakage Current
- High Surge Capability



Mechanical Data

- Case: D O - 4 1
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.35 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

DO-41		
Dim	**Min**	**Max**
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

RoHS COMPLIANT

Maximum Ratings @ T_A = 25°C unless otherwise specified

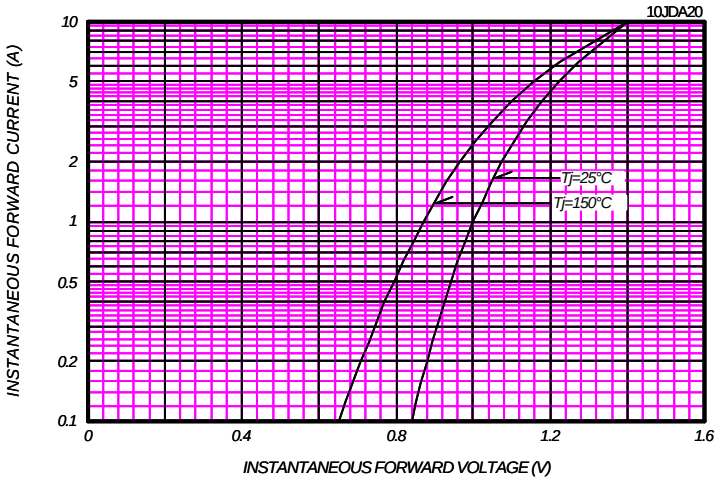
Rating	Symbol	10JDA20			Unit
Repetitive Peak Reverse Voltage	V_{RRM}	200			V
Average Rectified Output Current	I_O	50Hz Half Sine Wave Resistive Load	Ta=29 C *1	1.0	A
			Tl=126 C (Tl: Lead Temperature)	1.0	
RMS Forward Current	$I_{F(RMS)}$			1.57	A
Surge Forward Current	I_{FSM}	50Hz Half Sine Wave,1cycle, Non-repetitive		45	A
Operating JunctionTemperature Range	T_{jw}	- 40 to + 150			C
Storage Temperature Range	T_{stg}	- 40 to + 150			C

Electrical ● Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	Tj= 25 C, V_{RM}= V_{RRM}	-	-	10	A
Peak Forward Voltage	V_{FM}	Tj= 25 C, I_{FM}= 1.0A	-	-	1.0	V
Thermal Resistance	Rth(j-a)	Junction to Ambient *1	-	-	120	C/W
	Rth(j-l)	Junction to Lead	-	-	23	

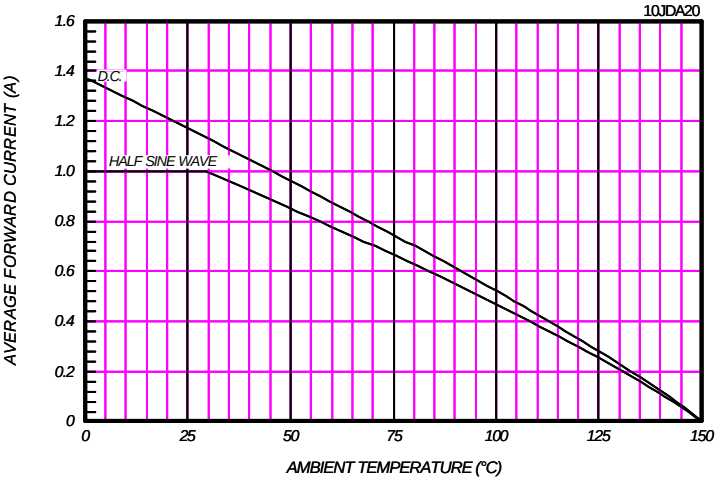
*1: Without Fin or P.C. Board mounted

FORWARD CURRENT VS. VOLTAGE

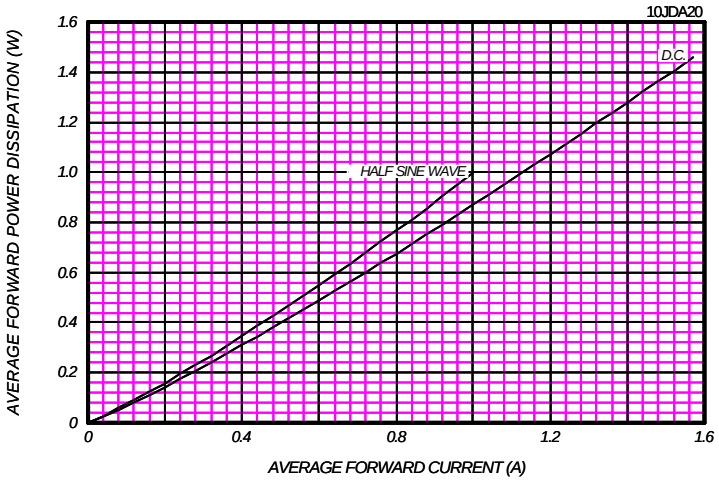


AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE

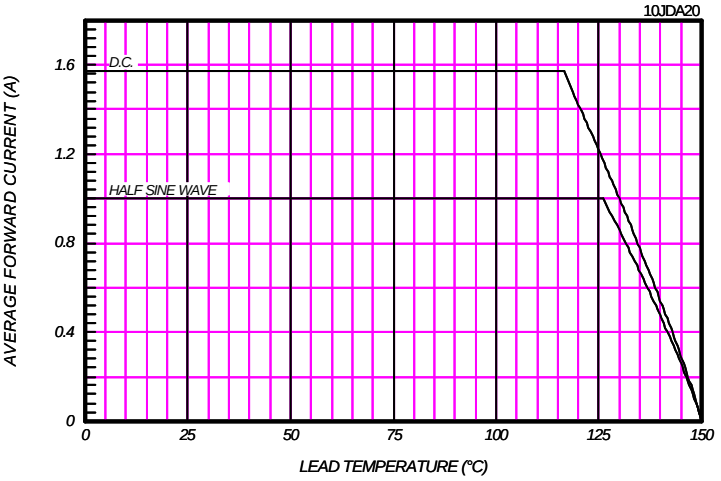
AMBIENT/Without Fin or P.C. Board



AVERAGE FORWARD POWER DISSIPATION



AVERAGE FORWARD CURRENT VS. LEAD TEMPERATURE



SURGE CURRENT RATINGS

f=50Hz,Harf Sine Wave,Non-Repetitive,No Load